UNISONIC TECHNOLOGIES CO., LTD

UP1452

Preliminary

NPN SILICON TRANSISTOR

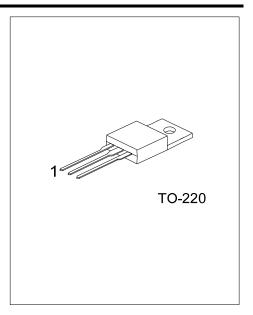
HIGH CURRENT LOW $V_{CE(SAT)}$ TRANSISTOR

DESCRIPTION

The UTC **UP1452** is specially designed to have high current and low $V_{\text{CE}(\text{SAT})}$ to suit for power amplifier application and power switching application.

■ FEATURES

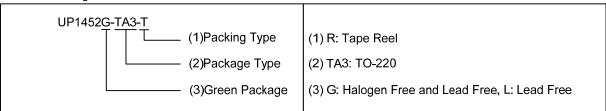
*Low Collector-Emitter Saturation Voltage: $V_{CE(SAT)} \le -0.4V$ (Max.) @ -6.0A



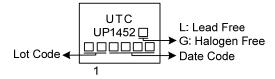
ORDERING INFORMATION

Ordering Number		Daalaaaa	Pin Assignment			Da alainan	
Lead Free	Halogen Free	Package	1	2	3	Packing	
UP1452L-TA3-T	UP1452G-TA3-T	TO-220	В	С	Е	Tube	

Note: Pin Assignment: B: Base C: Collector E: Emitter



MARKING



^{*} BV_{CEO} is -80V minimum

■ ABSOLUTE MAXIMUM RATINGS (T_A=25°C, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Collector-Base Voltage		V_{CBO}	-80	V
Collector-Emitter Voltage		V_{CEO}	-80	V
Emitter-Base Voltage		V_{EBO}	-6	V
O ti O - IIt O t	DC	Ic	-12	Α
Continuous Collector Current	Pulse	Icp	-15	Α
Continuous Base Current		I _B	-1	Α
Collector Power Dissipation		Pc	2	W
Junction Temperature		TJ	+150	°C
Storage Temperature		T _{STG}	-55 ~ +150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ ELECTRICAL CHARACTERISTICS (T_A=25°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Collector-Emitter Breakdown Voltage	BV _{CEO}	I _C =-50mA, I _B =0	-80			V
Collector Cut-Off Current	Ісво	V _{CB} =-80V, I _E =0			-5	μΑ
Emitter Cut-Off Current	I _{EBO}	V _{EB} =-6.0V, I _C =-0			-5	μΑ
DC Commant Cain	h _{FE1}	V _{CE} =-1.0V, I _C =-1.0A	120		240	
DC Current Gain	h _{FE2}	V _{CE} =-1.0V, I _C =-6.0A	40			
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	I _B =-0.3A, I _C =-6.0A		-0.14	-0.4	V
Base-Emitter Saturation Voltage	V _{BE(SAT)}	I _B =-0.3A, I _C =-6.0A		-0.9	-1.2	V
Base-Emitter on voltage	V_{BEON}	V _{CE} =-1.0V, I _C =-2.0A			-1.1	V
Transition Frequency	f⊤	V _{CE} =-5.0V, I _C =-1.0A		50		MHz

■ TEST CIRCUIT

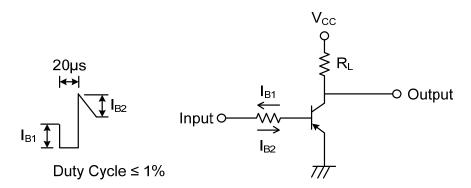


Figure 1.Switching Time Test Circuit

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